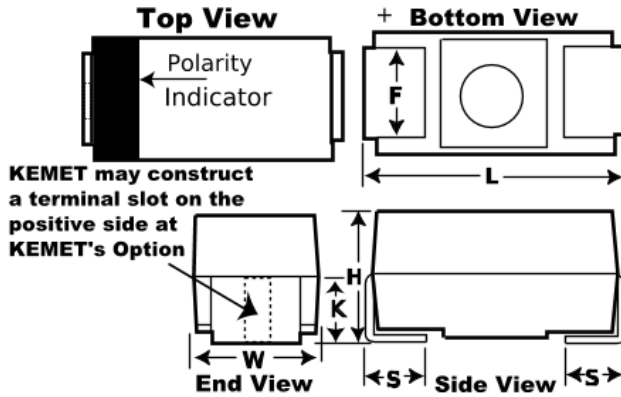


T498D336M010ZTE800

Obsolete

B45196P, Tantalum, MnO2 Tantalum, High Temperature, 33 uF, 20%, 10 VDC, SMD, Molded, High Temperature, N/A, 800 mOhms, 7343, 3.1mm



| General Information | |
|---------------------|-------------------------------|
| Series | B45196P |
| Dielectric | MnO2 Tantalum |
| Style | SMD Chip |
| Description | SMD, Molded, High Temperature |
| Features | High Temperature |
| RoHS | Yes |
| Termination | Tin |
| AEC-Q200 | No |

| Specifications | |
|-----------------------|---|
| Capacitance | 33 uF |
| Capacitance Tolerance | 20% |
| Voltage DC | 10 VDC (85C), 7.97 VDC (125C), 6.7 VDC (150C) |
| Temperature Range | -55/+150°C |
| Rated Temperature | 85°C |
| Dissipation Factor | 4.5% |
| Failure Rate | N/A |
| ESR | 0.8 Ohms (100kHz) |
| Leakage Current | 3.3 uA |

| Dimensions | |
|------------|----------------|
| Footprint | 7343 |
| L | 7.3mm +/-0.3mm |
| W | 4.3mm +/-0.3mm |
| H | 2.8mm +/-0.3mm |
| S | 1.3mm +/-0.3mm |
| F | 2.4mm +/-0.1mm |

| Packaging Specifications | |
|--------------------------|------------|
| Packaging | T&R, 178mm |
| Packaging Quantity | 750 |

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